

isc N-Channel MOSFET Transistor

AOK9N90

FEATURES

- Drain Current –I_D= 9A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 900V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 1.3 \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

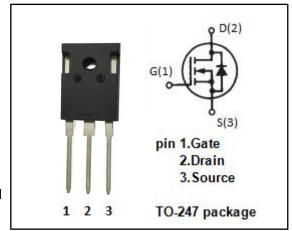
 Designed for use in switch mode power supplies and general purpose applications.

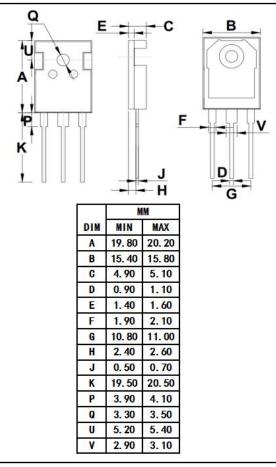
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER VALUE		UNIT
V _{DSS}	Drain-Source Voltage	900	V
V _{GS}	Gate-Source Voltage-Continuous ±30		V
I _D	Drain Current-Continuous 9		А
I _{DM}	Drain Current-Single Pluse 34		А
P _D	Total Dissipation @T _C =25℃	Dissipation @T _C =25℃ 368	
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$ C
T _{stg}	Storage Temperature	e Temperature -55~150	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.34	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	900		V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 5V; I _D = 0.25mA	3.4	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 4.5A		1.3	Ω
lgss	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0		±100	nA
l _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 900V; V _{GS} = 0 V _{DS} = 720V; V _{GS} = 0@T _J =125°C		1 10	μА
V _{SD}	Forward On-Voltage	I _S = 1A; V _{GS} = 0		1	V

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